

# 3.3V CMOS Static RAM 4 Meg (512K x 8-Bit)

#### Features

- 512K x 8 advanced high-speed CMOS Static RAM
- JEDEC Center Power / GND pinout for reduced noise
- Equal access and cycle times - Commercial and Industrial: 10/12/15ns
- Single 3.3V power supply
- One Chip Select plus one Output Enable pin
- ٠ Bidirectional data inputs and outputs directly TTL-compatible
- Low power consumption via chip deselect
- Available in 36-pin, 400 mil plastic SOJ package and 44-pin, 400 mil TSOP.
- Industrial temperature range (-40°C to +85°C) is available for selected speeds

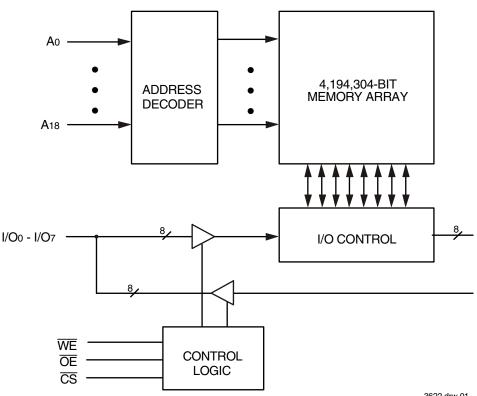
# Functional Block Diagram

## Description

The IDT71V424 is a 4,194,304-bit high-speed Static RAM organized as 512K x 8. It is fabricated using high-performance, high-reliability CMOS technology. This state-of-the-art technology, combined with innovative circuit design techniques, provides a cost-effective solution for high-speed memory needs.

The IDT71V424 has an output enable pin which operates as fast as 5ns, with address access times as fast as 10ns. All bidirectional inputs and outputs of the IDT71V424 are TTL-compatible and operation is from a single 3.3V supply. Fully static asynchronous circuitry is used, requiring no clocks or refresh for operation.

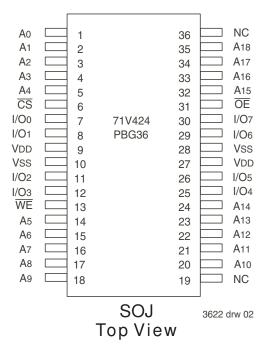
The IDT71V424 is packaged in a 36-pin, 400 mil Plastic SOJ and 44pin, 400 mil TSOP.



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# Pin Configurations<sup>(1)</sup>



#### NOTE:

1. This text does not indicate orientation of actual part-marking.

	1					1	
NC		1 (	$\supset$		44		NC
NC		2			43		NC
A0		3			42		NC
A1		4			41		A18
A2		5			40		A17
Аз		6			39		A16
A4		7			38		A15
$\overline{\text{CS}}$		8			37		ŌĒ
I/00		9			36		I/07
I/01		10		71V424	35		I/06
Vdd		11		PHG44	34		Vss
Vss		12			33		VDD
I/02		13			32		I/05
I/03		14			31		I/04
WE		15			30		A14
A5		16			29		A13
A6		17			28		A12
A7		18			27		A11
A8		19			26		A10
A9		20			25		NC
NC		21			24		NC
NC		22			23		NC
						]	
					362	22 drw	11

Top View

## **Pin Description**

A0 - A18	Address Inputs	Input
CS	Chip Select	Input
WE	Write Enable	Input
ŌĒ	Output Enable	Input
I/O0 - I/O7	Data Input/Output	I/O
Vdd	3.3V Power	Power
Vss	Ground	Gnd

3622 tbl 02

# Capacitance

(	TA =	+25°C.	f =	1.0MHz.	SOJ	package	)
	$I - \Lambda$	+20 0,	. –	1.011112,	000	paonago	

Symbol	Parameter <sup>(1)</sup>	Conditions	Max.	Unit	
CIN	Input Capacitance	VIN = 3dV	7	pF	
Cıvo	I/O Capacitance	Vout = 3dV	8	pF	
3622 tbl					

NOTE:

1. This parameter is guaranteed by device characterization, but not production tested.

#### Truth Table<sup>(1,2)</sup>

CS	ŌĒ	WE	I/O	Function			
L	L	Н	DATAOUT	Read Data			
L	Х	L	DATAIN	Write Data			
L	Н	Н	High-Z	Output Disabled			
Н	Х	Х	High-Z	Deselected - Standby (ISB)			
VHC <sup>(3)</sup>	х	х	High-Z	Deselected - Standby (ISB1)			
NOTES		3622 tbl					

NOTES:

1.  $H = V_{IH}, L = V_{IL}, x = Don't$  care.

2. VLC = 0.2V, VHC = VDD -0.2V.

3. Other inputs  $\geq V_{HC}$  or  $\leq V_{LC}$ .



## Absolute Maximum Ratings<sup>(1)</sup>

Symbol	Rating	Value	Unit
Vdd	Supply Voltage Relative to Vss	-0.5 to +4.6	V
Vin, Vout	Terminal Voltage Relative to Vss	-0.5 to VDD+0.5	V
TBIAS	Temperature Under Bias	-55 to +125	°C
Тѕтс	Storage Temperature	-55 to +125	°C
Ρτ	Power Dissipation	1	w
Ιουτ	DC Output Current	50	mA

#### NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Recommended Operating <u>Temperature and Supply Voltage</u>

Grade	Temperature	Vss	VDD
Commercial	0°C to +70°C	0V	See Below
Industrial	-40°C to +85°C	0V	See Below
			3622 tbl 05

# Recommended DC Operating Conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
Vdd	Supply Voltage	3.0	3.3	3.6	V
Vss	Ground	0	0	0	V
Vін	Input High Voltage	2.0		$V \text{DD} \textbf{+} \textbf{0.3}^{(1)}$	V
VIL	Input Low Voltage	-0.3 <sup>(2)</sup>		0.8	V

NOTES:

3622 tbl 04

1. VIH (max.) = VDD+2V for pulse width less than 5ns, once per cycle.

2. VIL (min.) = -2V for pulse width less than 5ns, once per cycle.

#### **DC Electrical Characteristics**

(VDD = Min. to Max., Commercial and Industrial Temperature Ranges)

			IDT71V424		
Symbol	Parameter	Test Condition	Min.	Min. Max. Unit	
lu	Input Leakage Current	VDD = Max., VIN = Vss to VDD		5	μA
Ilo	Output Leakage Current	VDD = Max., $\overline{CS}$ = VIH, VOUT = VSS to VDD		5	μA
Vol	Output Low Voltage	Iol = 8mA, Vdd = Min.	_	0.4	V
Vон	Output High Voltage	IOH = -4mA, VDD = Min.	2.4		V

3622 tbl 07

3622 tbl 06

## DC Electrical Characteristics<sup>(1, 2, 3)</sup>

(VDD = Min. to Max., VLC = 0.2V, VHC = VDD - 0.2V)

			71V424	IS/L 10	71V424	4S/L 12	71V424	S/L 15	Unit
Symbol	Parameter		Com'l.	Ind.	Com'l.	Ind.	Com'l.	Ind.	Unit
	Dynamic Operating Current	S	180	180	170	170	160	160	mA
lcc	$\overline{CS} \leq$ VLC, Outputs Open, VDD = Max., f = fmax <sup>(4)</sup>	L	165	165	155	155	145	145	mA
1	Dynamic Standby Power Supply Current	S	60	60	55	55	50	50	mA
ISB	$\overline{CS} \ge V$ HC, Outputs Open, VDD = Max., f = fMAX <sup>(4)</sup>	L	55	55	50	50	45	145 m 50 m 45 m	mA
	Full Standby Power Supply Current (static) $\overline{CS} \ge VHc$ , Outputs Open, VDD = Max., f = 0 <sup>(4)</sup>	S	20	20	20	20	20	20	mA
ISB1		L	10	10	10	10	10	10	mA

NOTES:

1. All values are maximum guaranteed values.

2. All inputs switch between 0.2V (Low) and  $V_{\text{DD}}$  - 0.2V (High).

3. Power specifications are preliminary.

4. fmax = 1/trc (all address inputs are cycling at fmax); f = 0 means no address input lines are changing.



Commercial and Industrial Temperature Ranges

## AC Test Conditions

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	1.5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	See Figure 1, 2 and 3

3622 tbl 09

# AC Test Loads

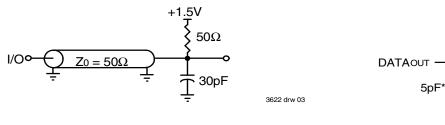
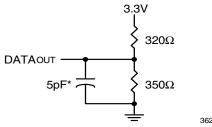


Figure 1. AC Test Load



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\*Including jig and scope capacitance.

Figure 2. AC Test Load (for tclz, tolz, tcHz, toHz, toHz, toW, and tWHz)

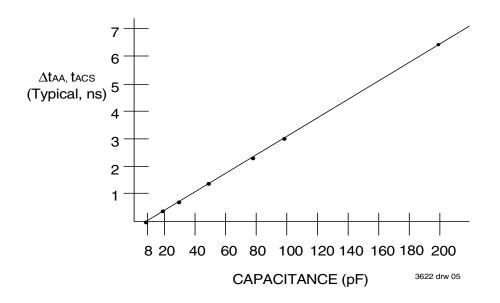


Figure 3. Output Capacitive Derating



3622 tbl 10

# AC Electrical Characteristics

 $(Vcc = 3.3V \pm 10\%, Commercial and Industrial Temperature Ranges)$ 

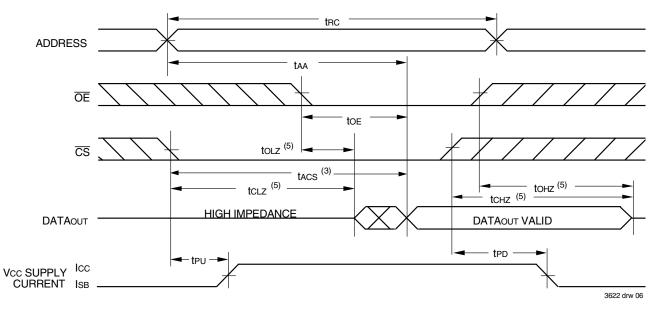
		71V42	24S/L10	71V424S/L12		71V424S/L15		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
READ CYCLE								
tRC	Read Cycle Time	10		12		15		ns
taa	Address Access Time		10		12		15	ns
tacs	Chip Select Access Time		10		12		15	ns
tcLZ <sup>(1)</sup>	Chip Select to Output in Low-Z	4		4		4		ns
tCHZ <sup>(1)</sup>	Chip Deselect to Output in High-Z		5		6		7	ns
tOE	Output Enable to Output Valid		5		6		7	ns
toLZ <sup>(1)</sup>	Output Enable to Output in Low-Z	0	—	0		0		ns
toHz <sup>(1)</sup>	Output Disable to Output in High-Z		5		6		7	ns
tон	Output Hold from Address Change	4		4		4		ns
tPU <sup>(1)</sup>	Chip Select to Power Up Time	0		0		0		ns
tPD <sup>(1)</sup>	Chip Deselect to Power Down Time		10		12		15	ns
WRITE CYCL	E							
twc	Write Cycle Time	10		12		15		ns
taw	Address Valid to End of Write	8		8		10		ns
tcw	Chip Select to End of Write	8		8		10		ns
tas	Address Set-up Time	0		0		0		ns
twp	Write Pulse Width	8		8		10		ns
twR	Write Recovery Time	0		0		0		ns
tow	Data Valid to End of Write	6		6		7		ns
tDH	Data Hold Time	0		0		0		ns
tow <sup>(1)</sup>	Output Active from End of Write	3	—	3		3		ns
twHz <sup>(1)</sup>	Write Enable to Output in High-Z		6		7		7	ns

NOTE:

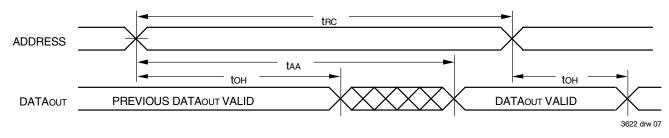
1. This parameter guaranteed with the AC load (Figure 2) by device characterization, but is not production tested.



# Timing Waveform of Read Cycle No. 1<sup>(1)</sup>



Timing Waveform of Read Cycle No. 2<sup>(1, 2, 4)</sup>



NOTES:

- 1.  $\overline{\text{WE}}$  is HIGH for Read Cycle.
- 2. Device is continuously selected,  $\overline{\text{CS}}$  is LOW.
- 3. Address must be valid prior to or coincident with the later of  $\overline{CS}$  transition LOW; otherwise tAA is the limiting parameter.

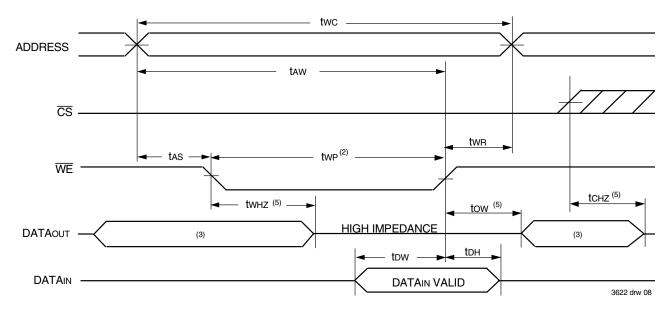
4.  $\overline{\text{OE}}$  is LOW.

5. Transition is measured  $\pm 200 \text{mV}$  from steady state.

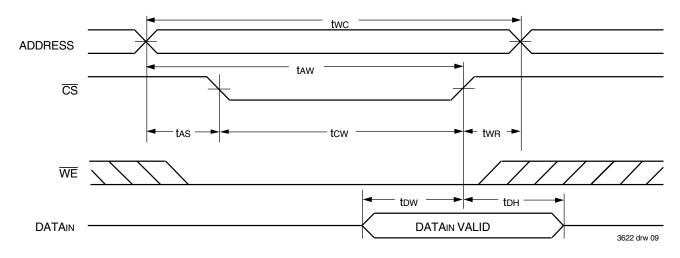




Timing Waveform of Write Cycle No. 1 (WE Controlled Timing)<sup>(1, 2, 4)</sup>



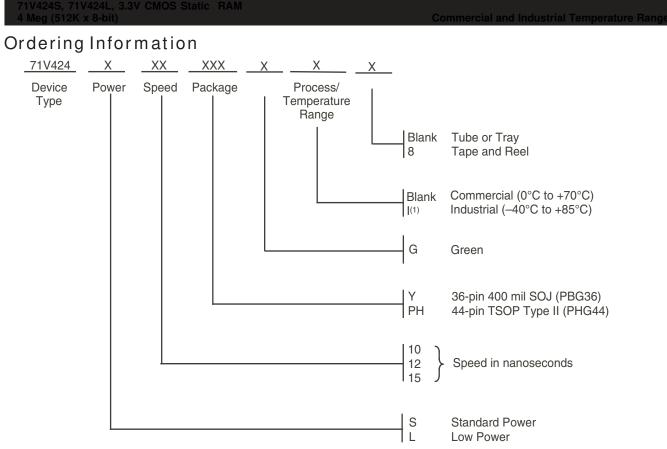
Timing Waveform of Write Cycle No. 2 (**CS** Controlled Timing)<sup>(1,4)</sup>



NOTES:

- 1. A write occurs during the overlap of a LOW  $\overline{\text{CS}}$  and a LOW  $\overline{\text{WE}}$ .
- 2. OE is continuously HIGH. During a WE controlled write cycle with OE LOW, twp must be greater than or equal to twHz + tow to allow the I/O drivers to turn off and data to be placed on the bus for the required tow. If OE is HIGH during a WE controlled write cycle, this requirement does not apply and the minimum write pulse is the specified twp.
- 3. During this period, I/O pins are in the output state, and input signals must not be applied.
- 4. If the CS LOW transition occurs simultaneously with or after the WE LOW transition, the outputs remain in a high impedance state. CS must be active during the tcw write period.
- 5. Transition is measured ±200mV from steady state.





#### NOTE:

1. Contact your local sales office for industrial temp. range for other speeds, packages and powers.

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Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
10	71V424L10PHG	PHG44	TSOP	С
	71V424L10PHG8	PHG44	TSOP	С
	71V424L10PHGI	PHG44	TSOP	I
	71V424L10PHGI8	PHG44	TSOP	I
	71V424L10YG	PBG36	SOJ	С
	71V424L10YG8	PBG36	SOJ	С
	71V424L10YGI	PBG36	SOJ	I
	71V424L10YGI8	PBG36	SOJ	I
12	71V424L12PHG	PHG44	TSOP	С
	71V424L12PHG8	PHG44	TSOP	С
	71V424L12PHGI	PHG44	TSOP	I
	71V424L12PHGI8	PHG44	TSOP	I
	71V424L12YG	PBG36	SOJ	С
	71V424L12YG8	PBG36	SOJ	С
	71V424L12YGI	PBG36	SOJ	I
	71V424L12YGI8	PBG36	SOJ	I
15	71V424L15PHG	PHG44	TSOP	С
	71V424L15PHG8	PHG44	TSOP	С
	71V424L15PHGI	PHG44	TSOP	I
	71V424L15PHGI8	PHG44	TSOP	I
	71V424L15YG	PBG36	SOJ	С
	71V424L15YG8	PBG36	SOJ	С
	71V424L15YGI	PBG36	SOJ	I
	71V424L15YGI8	PBG36	SOJ	I

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
10	71V424S10PHG	PHG44	TSOP	С
	71V424S10PHG8	PHG44	TSOP	С
	71V424S10PHGI	PHG44	TSOP	I
	71V424S10PHG18	PHG44	TSOP	I
	71V424S10YG	PBG36	SOJ	С
	71V424S10YG8	PBG36	SOJ	С
	71V424S10YGI	PBG36	SOJ	I
	71V424S10YGI8	PBG36	SOJ	I
12	71V424S12PHG	PHG44	TSOP	С
	71V424S12PHG8	PHG44	TSOP	С
	71V424S12PHGI	PHG44	TSOP	I
	71V424S12PHG18	PHG44	TSOP	I
	71V424S12YG	PBG36	SOJ	С
	71V424S12YG8	PBG36	SOJ	С
	71V424S12YGI	PBG36	SOJ	I
	71V424S12YGI8	PBG36	SOJ	I
15	71V424S15PHG	PHG44	TSOP	С
	71V424S15PHG8	PHG44	TSOP	С
	71V424S15PHGI	PHG44	TSOP	I
	71V424S15PHG18	PHG44	TSOP	I
	71V424S15YG	PBG36	SOJ	С
	71V424S15YG8	PBG36	SOJ	С
	71V424S15YGI	PBG36	SOJ	I
	71V424S15YGI8	PBG36	SOJ	I



# Datasheet Document History

8/13/99		Updated to new format
	Pg. 2	Removed SO44-1 from TSOP pinout
	Pg. 7	Revised footnotes on Write Cycle No. 1 diagram
		Removed footnote for twn on Write Cycle No. 2 diagram
	Pg. 9	Added Datasheet Document History
8/31/99	Pg. 1–9	Added Industrial temperature range offerings
11/22/02	Pg. 8	Added die revision option to ordering information
07/31/03	Pg. 8	Updated note, L10 speed grade commercial temperature only and updated die stepping from YF to Y.
07/28/04	Pg. 3	Increased ISB for all "L" and S15 speeds by 10mA and increased for S12 speed by 5mA (refer to
		PCN# SR-0402-02).
	Pg. 8	Added "Restricted hazardous substance device" to the ordering information.
09/20/08	Pg. 1, 8	Added Y and V step part numbers to front page and ordering information. Updated the ordering
		information by removing the "IDT" notation.
05/12/09	Pg. 3,5,8	Add Industrial grade for 10ns Low Power.
06/11/09	Pg.1,8	Removed VS, VL from datasheet and ordering information.
09/26/13:	Pg.1-9	Removed the /YS & /YL from the device name for the entire datasheet.
	Pg.1	Removed IDT's reference to fabrication.
	Pg.8	Updated ordering information by adding T&R, updated Restricted Hazardous Substance Device
		wording to Green and removed the Die Stepping Revision, the "Y" designator.
05/04/21	Pg.1-11	Rebranded as Renesas datasheet
	Pg.2 & 8	Updated package codes
	Pg.8	Added Industrial temp footnote to Ordering Information
	Pg.9	Added Orderable Part Information tables



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